、技术资料、百科信息、热点资讯,精彩子子子子子5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH +15-kV FSD (HRM) DROTECTION

SI S349 _ III	NE 1999	REVISED MARCH 2004

•	RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)		R PW PACH TOP VIEW)	
•	Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards	C2+[GND[-] C1+] V+
•	Operates With 3-V to 5.5-V V _{CC} Supply	C2-[
٠	Operates Up To 250 kbit/s	V-[C1-
	Five Drivers and Three Receivers	DOUT1[5 24	DIN1
•	Low Standby Current 1 μ A Typical	DOUT2		DIN2
•	External Capacitors $4 \times 0.1 \ \mu F$	DOUT3 RIN1] DIN3] ROUT1
٠	Accepts 5-V Logic Input With 3.3-V Supply	RIN2	9 20	ROUT2
•	Always-Active Noninverting Receiver	DOUT4[10 19	DIN4
	Output (ROUT1B)	RIN3[11 18	ROUT3
	Alternative High-Speed Pin-Compatible	DOUT5	12 17	DIN5
	Device (1 Mbit/s)	FORCEON	13 16	ROUT1B
	– SNx5C3238	FORCEOFF	14 15	INVALID
•	Applications Battery-Powered Systems, PDAs, 	·		I

description/ordering information

Modems, and Printers

Notebooks, Subnotebooks, Laptops, Palmtop PCs, Hand-Held Equipment,

The MAX3238 consists of five line drivers, three line receivers, and a dual charge-pump circuit with \pm 15-kV ESD (HBM) protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between notebook and subnotebook computer applications. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, the device includes an always-active noninverting output (ROUT1B), which allows applications using the ring indicator to transmit data while the device is powered down. These devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/ μ s driver output slew rate.

TA	PACKAGI	Eţ.	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		Tube of 50	MAX3238CDB	MAX20200
0°C to 70°C	SSOP (DB)	Reel of 2000	MAX3238CDBR	MAX3238C
–0°C to 70°C		Tube of 50	MAX3238CPW	14400000
	TSSOP (PW)	Reel of 2000	MAX3238CPWR	MA3238C
		Tube of 50	MAX3238IDB	
4000 1- 0500	SSOP (DB)	Reel of 2000	MAX3238IDBR	MAX3238I
–40°C to 85°C		Tube of 50	MAX3238IPW	MD20201
	TSSOP (PW)	Reel of 2000	MAX3238IPWR	MB3238I

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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description/ordering information (continued)

Flexible control options for power management are featured when the serial port and driver inputs are inactive. The auto-powerdown plus feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense valid signal transitions on all receiver and driver inputs for approximately 30 s, the built-in charge pump and drivers are powered down, reducing the supply current to 1 µA. By disconnecting the serial port or placing the peripheral drivers off, auto-powerdown plus occurs if there is no activity in the logic levels for the driver inputs. Auto-powerdown plus can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown plus enabled, the device activates automatically when a valid signal is applied to any receiver or driver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 µs. INVALID is low (invalid data) if all receiver input voltages are between -0.3 V and 0.3 V for more than 30 µs. Refer to Figure 5 for receiver input levels.

Function Tables

EACH DRIVER

		IN	PUTS	OUTPUT	
DIN	FORCEON	FORCEOFF	TIME ELAPSED SINCE LAST RIN OR DIN TRANSITION	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
н	н	Н	Х	L	auto-powerdown plus disabled
L	L	Н	<30 s	Н	Normal operation with
н	L	Н	<30 s	L	auto-powerdown plus enabled
L	L	Н	>30 s	Z	Powered off by
Н	L	Н	>30 s	Z	auto-powerdown plus feature

H = high level, L = low level, X = irrelevant, Z = high impedance

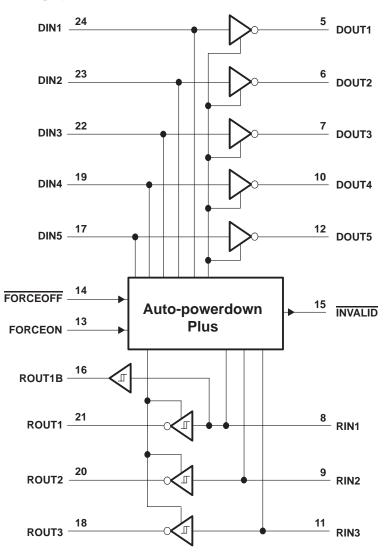
EACH RECEIVER

		INP	UTS	OUTP	UTS	
RIN1	RIN2-RIN3	FORCEOFF	TIME ELAPSED SINCE LAST RIN OR DIN TRANSITION	ROUT1B	ROUT	RECEIVER STATUS
L	Х	L	Х	L	Z	Powered off while
н	Х	L	Х	Н	Z	ROUT1B is active
L	L	Н	<30 s	L	Н	
L	Н	н	<30 s	L	L	Normal operation with
н	L	н	<30 s	Н	Н	auto-powerdown plus
н	Н	н	<30 s	Н	L	disabled/enabled
Open	Open	Н	>30 s	L	Н	

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off



logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC} (see Note 1) Positive output supply voltage range, V+ (see Note 1) Negative output supply voltage range, V- (see Note 1) Supply voltage difference, V+ - V- (see Note 1) Input voltage range, V ₁ : Driver (FORCEOFF, FORCEON) Receiver Output voltage range, V ₀ : Driver Receiver (INVALID)	-0.3 V to 7 V 0.3 V to -7 V 13 V -0.3 V to 6 V -0.3 V to 6 V -25 V to 25 V -13.2 V to 13.2 V -0.3 V to V _{CC} + 0.3 V
Package thermal impedance, θ _{JA} (see Notes 2 and 3): DB package PW package	
Operating virtual junction temperature, T _J Storage temperature range, T _{stg}	

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

- 2. Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 6)

				MIN	NOM	MAX	UNIT
			$V_{CC} = 3.3 V$	3	3.3	3.6	
	Supply voltage			4.5	5	5.5	V
V	Driver and control high-level input voltage		V _{CC} = 3.3 V	2			
VIH		DIN, FORCEOFF, FORCEON	$V_{CC} = 5 V$	2.4			V
VIL	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON				0.8	V
VI	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
VI	Receiver input voltage			-25		25	V
-				0		70	.
Τ _Α	Operating free-air temperature		MAX3238I	-40		85	°C

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP‡	MAX	UNIT	
Ц	Input leakage current	FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown plus disabled	No load, FORCEOFF and FORCEON at V_{CC}		0.5	2	mA
100	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
ICC	(T _A = 25°C)	Auto-powerdown plus enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

[‡] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TES	TEST CONDITIONS			TYP†	MAX	UNIT
∨он	High-level output voltage	All DOUT at RL = 3 k Ω to	GND		5	5.4		V
VOL	Low-level output voltage	All DOUT at RL = 3 k Ω to	All DOUT at $R_L = 3 \text{ k}\Omega$ to GND			-5.4		V
Iн	High-level input current	$V_{I} = V_{CC}$				±0.01	±1	μΑ
۱ _{IL}	Low-level input current	V _I at GND				±0.01	±1	μΑ
		V _{CC} = 3.6 V,	VO = 0 V			±35	±60	
los	Short-circuit output current‡	V _{CC} = 5.5 V,	VO = 0 V			±40	±100	mA
r _o	Output resistance	V _{CC} , V+, and V– = 0 V,	$V_{O} = \pm 2 V$		300	10M		Ω
1		$V_{O} = \pm 12 V$,	V_{CC} = 3 V to 3.6 V			±25		
loff	Output leakage current	Output leakage current FORCEOFF = GND		V_{CC} = 4.5 V to 5.5 V			±25	μA

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡] Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER TEST CONDITIONS			MIN	TYP†	MAX	UNIT
	Maximum data rate	C _L = 1000 pF, One DOUT switching,	R _L = 3 kΩ, See Figure 1	150	250		kbit/s
t _{sk(p)}	Pulse skew§	C _L = 150 pF to 2500 pF	R _L = 3 kΩ to 7 kΩ, See Figure 2		100		ns
SR(tr)	Slew rate, transition region	V _{CC} = 3.3 V,	$C_{L} = 150 \text{ pF} \text{ to } 1000 \text{ pF}$	6		30	Muo
SR(II)	(see Figure 1)	$V_{CC} = 3.3 \text{ V},$ R _L = 3 k Ω to 7 k Ω	C _L = 150 pF to 2500 pF	4		30	V/μs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

§ Pulse skew is defined as |tPLH - tPHL| of each channel of the same device.

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	I _{OH} = -1 mA	V _{CC} -0.6 V	V _{CC} -0.1 V		V
VOL	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
×	Desitive as is a issue thread and us to as	V _{CC} = 3.3 V		1.5	2.4	V
V _{IT+}	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.8	2.4	V
	Manual theory and the state of the second state of the second	V _{CC} = 3.3 V	0.6	1.2		
V _{IT} –	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.5		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT–})			0.3		V
loff	Output leakage current (except ROUT1B)	FORCEOFF = 0 V		±0.05	±10	μΑ
rj	Input resistance	$V_I = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4)

	PARAMETER	TEST CONDITIONS	ΜΙΝ ΤΥΡ [†] ΜΑΧ	UNIT
^t PLH	Propagation delay time, low- to high-level output		150	ns
^t PHL	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	150	ns
ten	Output enable time		200	ns
^t dis	Output disable time	$C_{L} = 150 \text{ pF}, R_{L} = 3 \text{ k}\Omega$, See Figure 4	200	ns
^t sk(p)	Pulse skew [‡]	See Figure 3	50	ns

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

 \ddagger Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

NOTE 4: Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



AUTO-POWERDOWN PLUS SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VT+(valid)	Re <u>ceiver in</u> put threshold for INVALID high-level output voltage	$\frac{\text{FORCEON}}{\text{FORCEOFF}} = \text{ORD},$			2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	$\frac{\text{FORCEON}}{\text{FORCEOFF}} = \text{V}_{\text{CC}}$	-2.7			V
VT(invalid)	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-0.3		0.3	V
VOH	INVALID high-level output voltage	$I_{OH} = -1 \text{ mA}$, FORCEON = GND, FORCEOFF = V _{CC}	V _{CC} -0.6			V
VOL	INVALID low-level output voltage	$I_{OL} = 1.6 \text{ mA}$, FORCEON = GND, FORCEOFF = V _{CC}			0.4	V

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	MIN	TYP†	MAX	UNIT
^t valid	Propagation delay time, low- to high-level output		0.1		μs
^t invalid	Propagation delay time, high- to low-level output		50		μs
t _{en}	Supply enable time		25		μs
t _{dis}	Receiver or driver edge to auto-powerdown plus	15	30	60	S

[†] All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}$ C.

PARAMETER MEASUREMENT INFORMATION

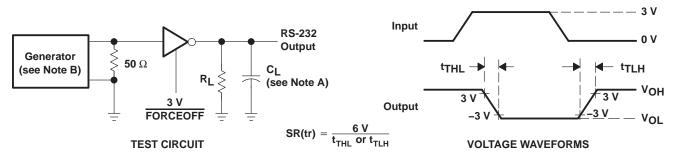
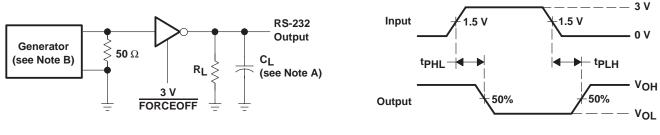




Figure 1. Driver Slew Rate



PARAMETER MEASUREMENT INFORMATION



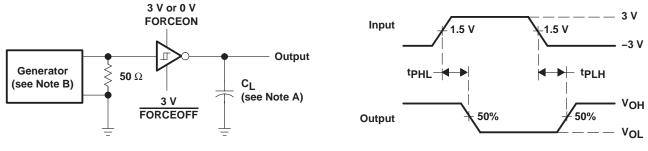
TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. CI includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_{O} = 50 Ω , 50% duty cycle, $t_{r} \le 10$ ns, $t_{f} \le 10$ ns.

Figure 2. Driver Pulse Skew



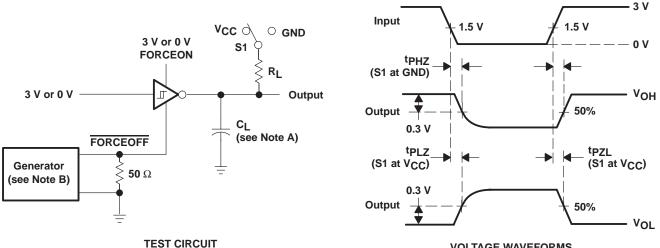
TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. CL includes probe and jig capacitance.

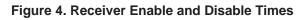
B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



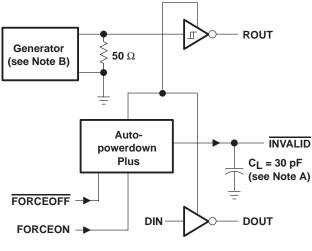
VOLTAGE WAVEFORMS

- NOTES: A. $C_{\mbox{L}}$ includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns, $t_f \le 10$ ns.
 - C. tPLZ and tPHZ are the same as tdis.
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

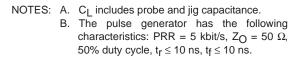


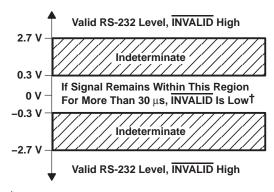


PARAMETER MEASUREMENT INFORMATION

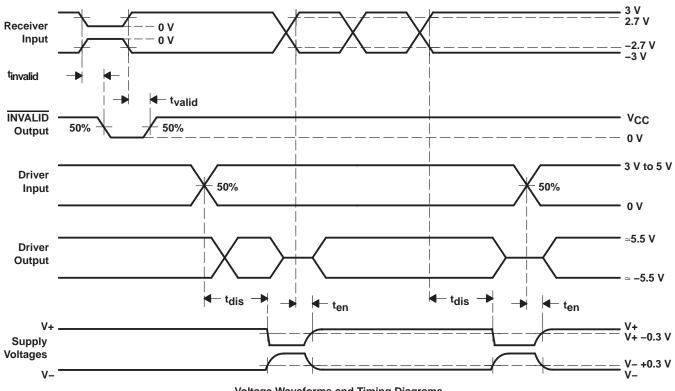


TEST CIRCUIT





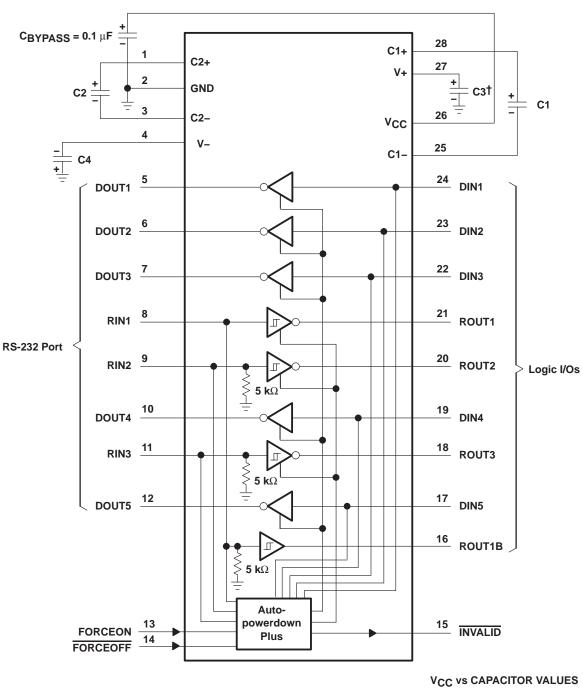
[†]Auto-powerdown plus disables drivers and reduces supply current to 1 µA.



Voltage Waveforms and Timing Diagrams

Figure 5. INVALID Propagation-Delay Times and Supply-Enabling Time





APPLICATION INFORMATION

 $^{+}$ C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V _{CC}	C1	C2, C3, and C4
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.15 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.22 μF 0.047 μF 0.22 μF	0.1 μF 0.22 μF 0.33 μF 1 μF





5-Dec-2005

PACKAGING INFORMATION

MENTS

www ti com

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX3238CDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238CDBE4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238CDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238CDBRE4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238CDBRG4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
MAX3238CPW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238CPWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IDBE4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IDBRE4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IPW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IPWE4	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IPWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3238IPWRE4	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM



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MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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